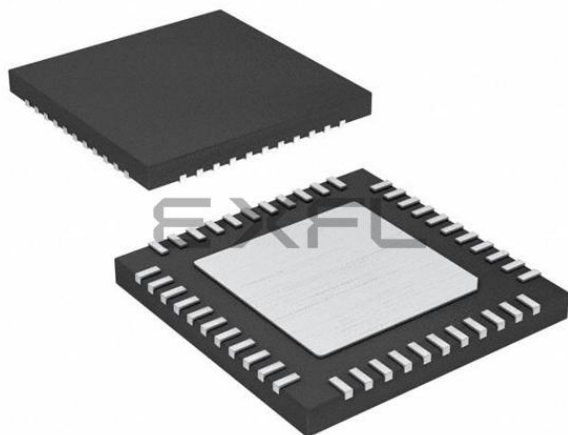




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What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Active
Core Processor	AVR
Core Size	8/16-Bit
Speed	32MHz
Connectivity	I ² C, IrDA, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, POR, PWM, WDT
Number of I/O	34
Program Memory Size	128KB (64K x 16)
Program Memory Type	FLASH
EEPROM Size	2K x 8
RAM Size	8K x 8
Voltage - Supply (Vcc/Vdd)	1.6V ~ 3.6V
Data Converters	A/D 12x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	44-VFQFN Exposed Pad
Supplier Device Package	44-VQFN (7x7)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/atxmega128d4-mh

Ordering Code	Flash (Bytes)	EEPROM (Bytes)	SRAM (Bytes)	Speed (MHz)	Power Supply	Package ⁽¹⁾⁽²⁾⁽³⁾	Temp	
ATxmega128D4-AN	128K + 8K	2K	8K	32	1.6 - 3.6V	44A	-40°C - 105°C	
ATxmega128D4-ANR ⁽⁴⁾	128K + 8K	2K	8K					
ATxmega64D4-AN	64K + 4K	2K	4K					
ATxmega64D4-ANR ⁽⁴⁾	64K + 4K	2K	4K					
ATxmega32D4-AN	32K + 4K	1K	4K					
ATxmega32D4-ANR ⁽⁴⁾	32K + 4K	1K	4K					
ATxmega16D4-AN	16K + 4K	1K	2K					
ATxmega16D4-ANR ⁽⁴⁾	16K + 4K	1K	2K					
ATxmega128D4-M7	128K + 8K	2K	8K			44M1		
ATxmega128D4-M7R ⁽⁴⁾	128K + 8K	2K	8K					
ATxmega64D4-M7	64K + 4K	2K	4K					
ATxmega64D4-M7R ⁽⁴⁾	64K + 4K	2K	4K					
ATxmega32D4-M7	32K + 4K	1K	4K					
ATxmega32D4-M7R ⁽⁴⁾	32K + 4K	1K	4K					
ATxmega16D4-M7	16K + 4K	1K	2K					
ATxmega16D4-M7R ⁽⁴⁾	16K + 4K	1K	2K					

- Notes:
1. This device can also be supplied in wafer form. Please contact your local Atmel sales office for detailed ordering information.
 2. Pb-free packaging, complies to the European Directive for Restriction of Hazardous Substances (RoHS directive). Also Halide free and fully Green.
 3. For packaging information see ["Packaging information" on page 64](#).
 4. Tape and Reel.

Package type	
44A	44-lead, 10*10mm body size, 1.0mm body thickness, 0.8mm lead pitch, thin profile plastic quad flat package (TQFP)
44M1	44-Pad, 7*7*1mm body, lead pitch 0.50mm, 5.20mm exposed pad, thermally enhanced plastic very thin quad no lead package (VQFN)
49C2	49-ball (7 * 7 Array), 0.65mm pitch, 5.0*5.0*1.0mm, very thin, fine-pitch ball grid array package (VFBGA)

Typical Applications

Industrial control	Climate control	Low power battery applications
Factory automation	RF and ZigBee®	Power tools
Building control	USB connectivity	HVAC
Board control	Sensor control	Utility metering
White goods	Optical	Medical applications

3. Overview

The Atmel AVR XMEGA is a family of low power, high performance, and peripheral rich 8/16-bit microcontrollers based on the AVR enhanced RISC architecture. By executing instructions in a single clock cycle, the AVR XMEGA device achieves throughputs CPU approaching one million instructions per second (MIPS) per megahertz, allowing the system designer to optimize power consumption versus processing speed.

The AVR CPU combines a rich instruction set with 32 general purpose working registers. All 32 registers are directly connected to the arithmetic logic unit (ALU), allowing two independent registers to be accessed in a single instruction, executed in one clock cycle. The resulting architecture is more code efficient while achieving throughputs many times faster than conventional single-accumulator or CISC based microcontrollers.

The AVR XMEGA D4 devices provide the following features: in-system programmable flash with read-while-write capabilities; internal EEPROM and SRAM; four-channel event system and programmable multilevel interrupt controller, 34 general purpose I/O lines, 16-bit real-time counter (RTC); four flexible, 16-bit timer/counters with compare and PWM channels; two USARTs; two two-wire serial interfaces (TWIs); two serial peripheral interfaces (SPIs); one twelve-channel, 12-bit ADC with optional differential input with programmable gain; two analog comparators (ACs) with window mode; programmable watchdog timer with separate internal oscillator; accurate internal oscillators with PLL and prescaler; and programmable brown-out detection.

The program and debug interface (PDI), a fast, two-pin interface for programming and debugging, is available.

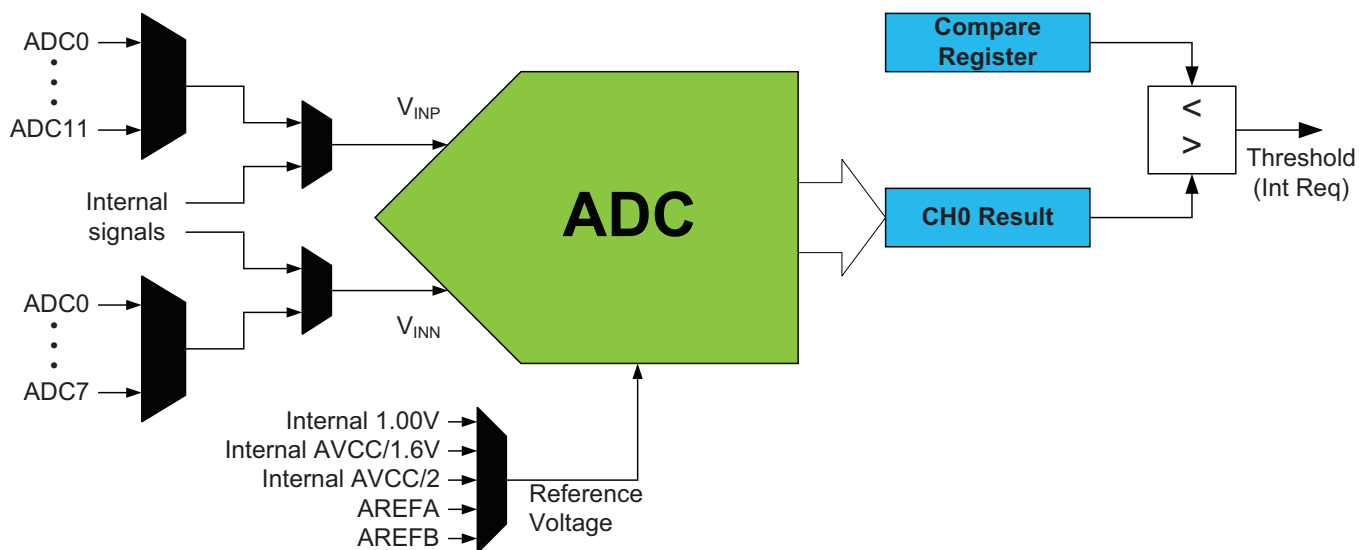
The XMEGA D4 devices have five software selectable power saving modes. The idle mode stops the CPU while allowing the SRAM, event system, interrupt controller, and all peripherals to continue functioning. The power-down mode saves the SRAM and register contents, but stops the oscillators, disabling all other functions until the next TWI, or pin-change interrupt, or reset. In power-save mode, the asynchronous real-time counter continues to run, allowing the application to maintain a timer base while the rest of the device is sleeping. In standby mode, the external crystal oscillator keeps running while the rest of the device is sleeping. This allows very fast startup from the external crystal, combined with low power consumption. In extended standby mode, both the main oscillator and the asynchronous timer continue to run. To further reduce power consumption, the peripheral clock to each individual peripheral can optionally be stopped in active mode and idle sleep mode.

Atmel offers a free QTouch library for embedding capacitive touch buttons, sliders and wheels functionality into AVR microcontrollers.

The devices are manufactured using Atmel high-density, nonvolatile memory technology. The program flash memory can be reprogrammed in-system through the PDI interface. A boot loader running in the device can use any interface to download the application program to the flash memory. The boot loader software in the boot flash section will continue to run while the application flash section is updated, providing true read-while-write operation. By combining an 8/16-bit RISC CPU with in-system, self-programmable flash, the AVR XMEGA is a powerful microcontroller family that provides a highly flexible and cost effective solution for many embedded applications.

All Atmel AVR XMEGA devices are supported with a full suite of program and system development tools, including C compilers, macro assemblers, program debugger/simulators, programmers, and evaluation kits.

Figure 25-1. ADC overview



The ADC may be configured for 8- or 12-bit result, reducing the minimum conversion time (propagation delay) from 5.0 μ s for 12-bit to 3.6 μ s for 8-bit result.

ADC conversion results are provided left- or right adjusted with optional '1' or '0' padding. This eases calculation when the result is represented as a signed integer (signed 16-bit number).

Notation of this peripheral is ADCA. The PORTA has ADCA inputs 0..7 and PORTB has ADCA inputs 8..11.

Table 28-3. Port C - Alternate Functions

PORT C	PIN#	INTERRUPT	TCC0 ⁽¹⁾⁽²⁾	AWEXC	TCC1	USARTC0 ⁽³⁾	SPIC ⁽⁴⁾	TWIC	CLOCKOUT ⁽⁵⁾	EVENTOUT ⁽⁶⁾
GND	8									
VCC	9									
PC0	10	SYNC	OC0A	OC0ALS				SDA		
PC1	11	SYNC	OC0B	OC0AHS		XCK0		SCL		
PC2	12	SYNC/ASYNC	OC0C	OC0BLS		RXD0				
PC3	13	SYNC	OC0D	OC0BHS		TXD0				
PC4	14	SYNC		OC0CLS	OC1A		SS			
PC5	15	SYNC		OC0CHS	OC1B		MOSI			
PC6	16	SYNC		OC0DLS			MISO		clk _{RTC}	
PC7	17	SYNC		OC0DHS			SCK		clk _{PER}	EVOUT

- Notes:
1. Pin mapping of all TC0 can optionally be moved to high nibble of port
 2. If TC0 is configured as TC2 all eight pins can be used for PWM output.
 3. Pin mapping of all USART0 can optionally be moved to high nibble of port.
 4. Pins MOSI and SCK for all SPI can optionally be swapped.
 5. CLKOUT can optionally be moved between port C, D and E and between pin 4 and 7.
 6. EVOUT can optionally be moved between port C, D and E and between pin 4 and 7.

Table 28-4. Port D - Alternate Functions

PORT D	PIN #	INTERRUPT	TCD0	USARTD0	SPID	CLOCKOUT	EVENTOUT
GND	18						
VCC	19						
PD0	20	SYNC	OC0A				
PD1	21	SYNC	OC0B	XCK0			
PD2	22	SYNC/ASYNC	OC0C	RXD0			
PD3	23	SYNC	OC0D	TXD0			
PD4	24	SYNC			SS		
PD5	25	SYNC			MOSI		
PD6	26	SYNC			MISO		
PD7	27	SYNC			SCK	clk _{PER}	EVOUT

Table 28-5. Port E - Alternate Functions

PORT E	PIN #	INTERRUPT	TCE0	TWIE
PE0	28	SYNC	OC0A	SDA
PE1	29	SYNC	OC0B	SCL
GND	30			

32.1.6 ADC Characteristics

Table 32-8. Power Supply, Reference and Input Range

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
AV_{CC}	Analog supply voltage		$V_{CC} - 0.3$		$V_{CC} + 0.3$	V
V_{REF}	Reference voltage		1		$AV_{CC} - 0.6$	
R_{in}	Input resistance	Switched			4.5	k Ω
C_{in}	Input capacitance	Switched			5	pF
R_{AREF}	Reference input resistance	(leakage only)		>10		M Ω
C_{AREF}	Reference input capacitance	Static load		7		pF
V_{in}	Input range		0		V_{REF}	V
	Conversion range	Differential mode, $V_{inp} - V_{inn}$	$-V_{REF}$		V_{REF}	
	Conversion range	Single ended unsigned mode, V_{inp}	$-\Delta V$		$V_{REF} - \Delta V$	
ΔV	Fixed offset voltage			200		LSB

Table 32-9. Clock and Timing

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
Clk_{ADC}	ADC clock frequency	Maximum is 1/4 of peripheral clock frequency	100		1800	kHz
		Measuring internal signals		125		
f_{ClkADC}	Sample rate		16		300	ksps
f_{ADC}	Sample rate	Current limitation (CURRLIMIT) off			300	
		CURRLIMIT = LOW			250	
		CURRLIMIT = MEDIUM			150	
		CURRLIMIT = HIGH			50	
	Sampling time	Configurable in steps of 1/2 Clk_{ADC} cycles up to 32 Clk_{ADC} cycles	0.28		320	μs
	Conversion time (latency)	(RES+1)/2 + GAIN RES (Resolution) = 8 or 12, GAIN=0 to 3	4.5		10	Clk_{ADC} cycles
	Start-up time	ADC clock cycles		12	24	
	ADC settling time	After changing reference or input mode		7	7	

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
R _Q	Negative impedance	XOSCPWR=1, FRQRANGE=1, CL=20pF	9MHz crystal	1500		Ω
			12MHz crystal	650		
			16MHz crystal	270		
		XOSCPWR=1, FRQRANGE=2, CL=20pF	12MHz crystal	1000		
			16MHz crystal	440		
		XOSCPWR=1, FRQRANGE=3, CL=20pF	12MHz crystal	1300		
			16MHz crystal	590		
	ESR	SF = safety factor			min(R _Q)/SF	kΩ
	Start-up time	XOSCPWR=0, FRQRANGE=0	0.4MHz resonator, CL=100pF	1.0		ms
		XOSCPWR=0, FRQRANGE=1	2MHz crystal, CL=20pF	2.6		
		XOSCPWR=0, FRQRANGE=2	8MHz crystal, CL=20pF	0.8		
		XOSCPWR=0, FRQRANGE=3	12MHz crystal, CL=20pF	1.0		
		XOSCPWR=1, FRQRANGE=3	16MHz crystal, CL=20pF	1.4		
C _{XTAL1}	Parasitic capacitance XTAL1 pin			5.9		pF
C _{XTAL2}	Parasitic capacitance XTAL2 pin			8.3		
C _{LOAD}	Parasitic capacitance load			3.5		

32.1.13.8 External 32.768kHz Crystal Oscillator and TOSC Characteristics

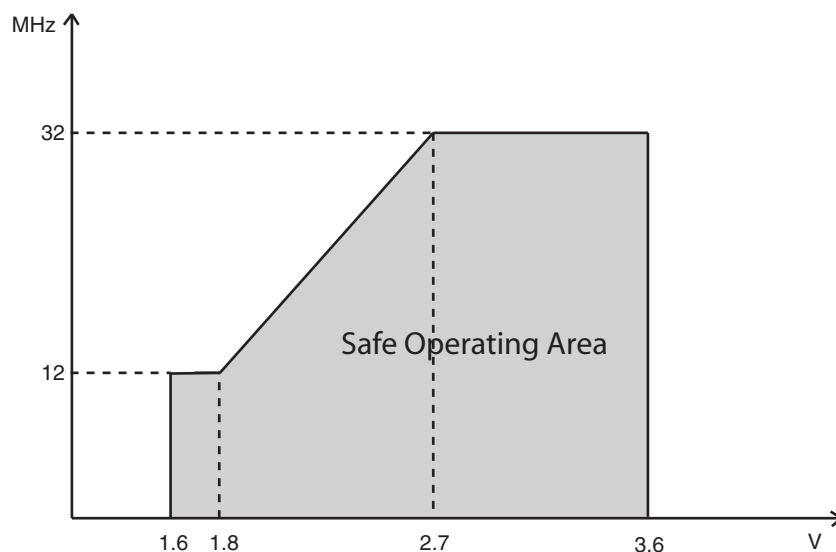
Table 32-26. External 32.768kHz Crystal Oscillator and TOSC Characteristics

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
ESR/R1	Recommended crystal equivalent series resistance (ESR)	Crystal load capacitance 6.5pF			60	kΩ
		Crystal load capacitance 9.0pF			35	
		Crystal load capacitance 12pF			28	
C _{TOSC1}	Parasitic capacitance TOSC1 pin			3.5		pF
C _{TOSC2}	Parasitic capacitance TOSC2 pin			3.5		
	Recommended safety factor	capacitance load matched to crystal specification	3			

Note: See [Figure 32-4](#) for definition.

The maximum CPU clock frequency depends on V_{CC} . As shown in [Figure 32-15](#) the Frequency vs. V_{CC} curve is linear between $1.8V < V_{CC} < 2.7V$.

Figure 32-15. Maximum Frequency vs. V_{CC}



32.3.13.3 Calibrated and Tunable 32MHz Internal Oscillator Characteristics

Table 32-77. 32MHz Internal Oscillator Characteristics

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
	Frequency range	DFLL can tune to this frequency over voltage and temperature	30		55	MHz
	Factory calibrated frequency			32		
	Factory calibration accuracy	T = 85°C, V _{CC} = 3.0V	-1.5		1.5	%
	User calibration accuracy		-0.2		0.2	
	DFLL calibration step size			0.22		

32.3.13.4 32kHz Internal ULP Oscillator Characteristics

Table 32-78. 32kHz Internal ULP Oscillator Characteristics

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
	Factory calibrated frequency			32		kHz
	Factory calibration accuracy	T = 85°C, V _{CC} = 3.0V	-12		12	%
	Accuracy		-30		30	

32.3.13.5 Internal Phase Locked Loop (PLL) Characteristics

Table 32-79. Internal PLL Characteristics

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
f _{IN}	Input frequency	Output frequency must be within f _{OUT}	0.4		64	MHz
f _{OUT}	Output frequency ⁽¹⁾	V _{CC} = 1.6 - 1.8V	20		48	
		V _{CC} = 2.7 - 3.6V	20		128	
	Start-up time			25		μs
	Re-lock time			25		

Note: 1. The maximum output frequency vs. supply voltage is linear between 1.8V and 2.7V, and can never be higher than four times the maximum CPU frequency.

32.3.13.6 External Clock Characteristics

Figure 32-17. External Clock Drive Waveform

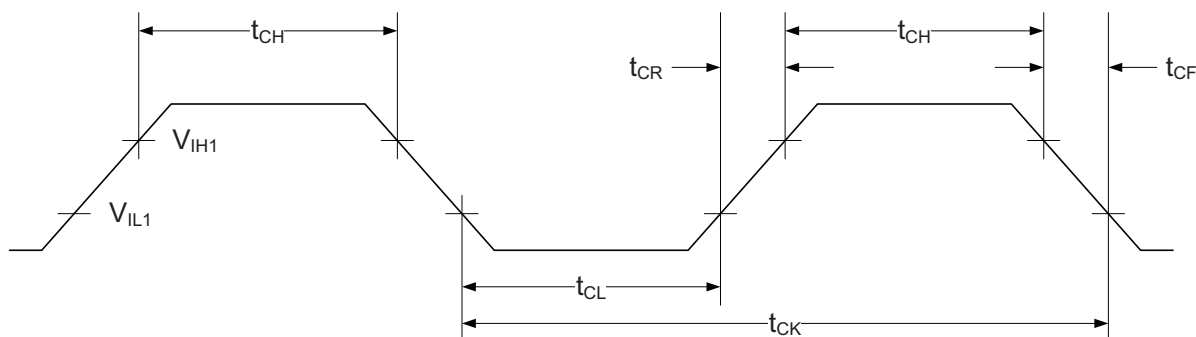


Table 32-80. External Clock Used as System Clock without Prescaling

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
$1/t_{CK}$	Clock frequency ⁽¹⁾	$V_{CC} = 1.6 - 1.8V$	0		12	MHz
		$V_{CC} = 2.7 - 3.6V$	0		32	
t_{CK}	Clock period	$V_{CC} = 1.6 - 1.8V$	83.3			ns
		$V_{CC} = 2.7 - 3.6V$	31.5			
t_{CH}	Clock high time	$V_{CC} = 1.6 - 1.8V$	30.0			
		$V_{CC} = 2.7 - 3.6V$	12.5			
t_{CL}	Clock low time	$V_{CC} = 1.6 - 1.8V$	30.0			
		$V_{CC} = 2.7 - 3.6V$	12.5			
t_{CR}	Rise time (for maximum frequency)	$V_{CC} = 1.6 - 1.8V$			10	
		$V_{CC} = 2.7 - 3.6V$			3	
t_{CF}	Fall time (for maximum frequency)	$V_{CC} = 1.6 - 1.8V$			10	
		$V_{CC} = 2.7 - 3.6V$			3	
Δt_{CK}	Change in period from one clock cycle to the next				10	%

Note: 1. System Clock Prescalers must be set so that maximum CPU clock frequency for device is not exceeded.

Table 32-84. SPI Timing Characteristics and Requirements

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
t_{SCK}	SCK period	Master		(See Table 17-4 in XMEGA D Manual)		ns
t_{SCKW}	SCK high/low width	Master		$0.5 \cdot SCK$		
t_{SCKR}	SCK rise time	Master		2.7		
t_{SCKF}	SCK fall time	Master		2.7		
t_{MIS}	MISO setup to SCK	Master		10		
t_{MIH}	MISO hold after SCK	Master		10		
t_{MOS}	MOSI setup SCK	Master		$0.5 \cdot SCK$		
t_{MOH}	MOSI hold after SCK	Master		1		
t_{SSCK}	Slave SCK period	Slave	$4 \cdot t_{Clk_{PER}}$			
t_{SSCKW}	SCK high/low width	Slave	$2 \cdot t_{Clk_{PER}}$			
t_{SSCKR}	SCK rise time	Slave			1600	
t_{SSCKF}	SCK fall time	Slave			1600	
t_{SIS}	MOSI setup to SCK	Slave	3			
t_{SIH}	MOSI hold after SCK	Slave	$t_{Clk_{PER}}$			
t_{SSS}	$\overline{SS}$ setup to SCK	Slave	21			
t_{SSH}	$\overline{SS}$ hold after SCK	Slave	20			
t_{SOS}	MISO setup SCK	Slave		8.0		
t_{SOH}	MISO hold after SCK	Slave		13.0		
t_{SOSS}	MISO setup after $\overline{SS}$ low	Slave		11.0		
t_{SOSH}	MISO hold after $\overline{SS}$ high	Slave		8.0		

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
$t_{HD;STA}$	Hold time (repeated) START condition	$f_{SCL} \leq 100kHz$	4.0			μs
		$f_{SCL} > 100kHz$	0.6			
t_{LOW}	Low period of SCL clock	$f_{SCL} \leq 100kHz$	4.7			
		$f_{SCL} > 100kHz$	1.3			
t_{HIGH}	High period of SCL clock	$f_{SCL} \leq 100kHz$	4.0			
		$f_{SCL} > 100kHz$	0.6			
$t_{SU;STA}$	Set-up time for a repeated START condition	$f_{SCL} \leq 100kHz$	4.7			
		$f_{SCL} > 100kHz$	0.6			
$t_{HD;DAT}$	Data hold time	$f_{SCL} \leq 100kHz$	0		3.45	μs
		$f_{SCL} > 100kHz$	0		0.9	
$t_{SU;DAT}$	Data setup time	$f_{SCL} \leq 100kHz$	250			ns
		$f_{SCL} > 100kHz$	100			
$t_{SU;STO}$	Setup time for STOP condition	$f_{SCL} \leq 100kHz$	4.0			μs
		$f_{SCL} > 100kHz$	0.6			
t_{BUF}	Bus free time between a STOP and START condition	$f_{SCL} \leq 100kHz$	4.7			μs
		$f_{SCL} > 100kHz$	1.3			

- Notes:
1. Required only for $f_{SCL} > 100kHz$.
 2. C_b = Capacitance of one bus line in pF.
 3. f_{PER} = Peripheral clock frequency.

33.2.1.3 Power-down Mode Supply Current

Figure 33-94. Power-down Mode Supply Current vs. V_{CC}
All functions disabled

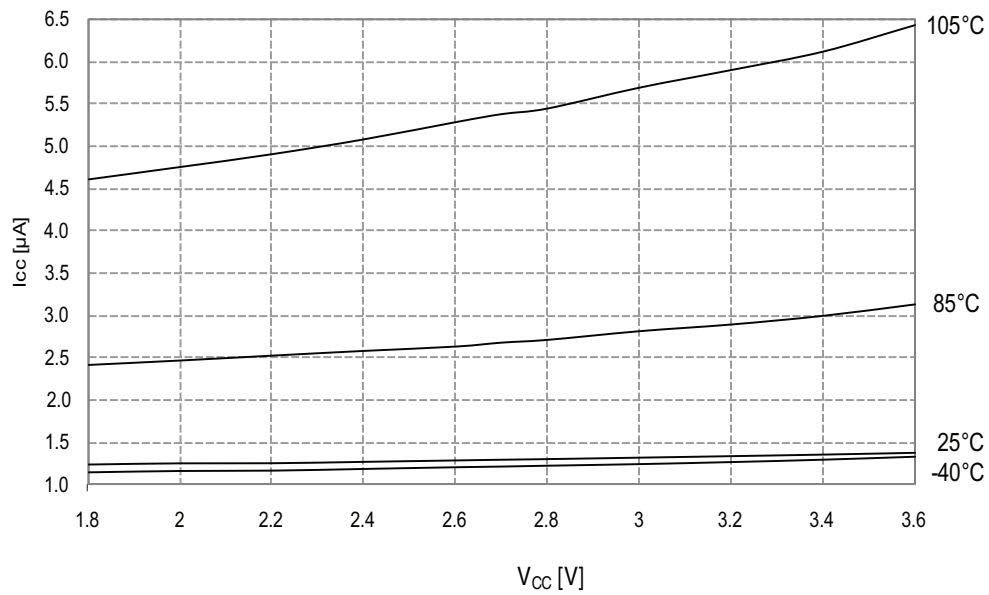


Figure 33-95. Power-down Mode Supply Current vs. V_{CC}
Watchdog and sampled BOD enabled

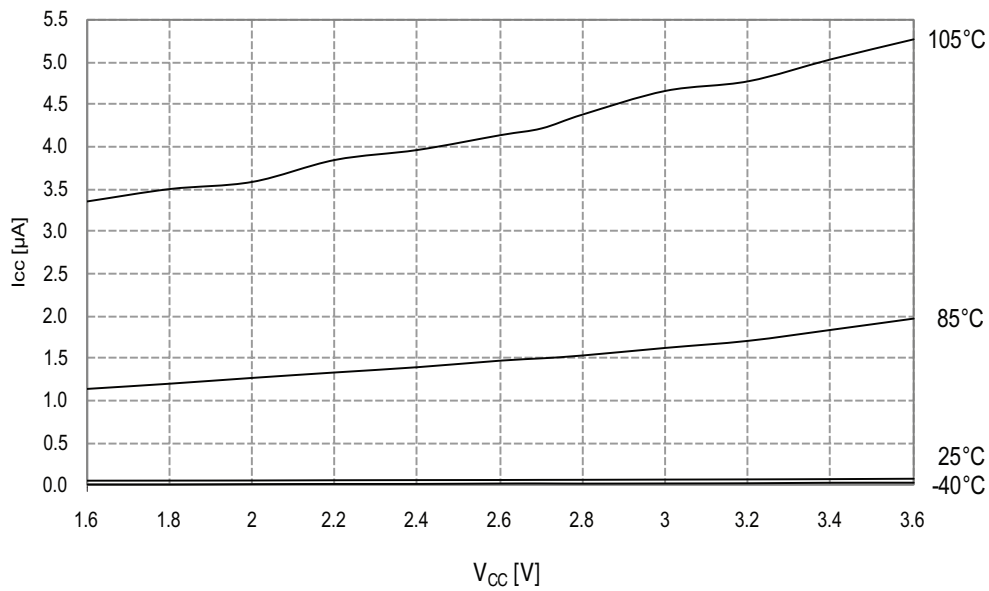


Figure 33-140. Reset Pin Input Threshold Voltage vs. V_{CC}

V_{IH} - Reset pin read as "1"

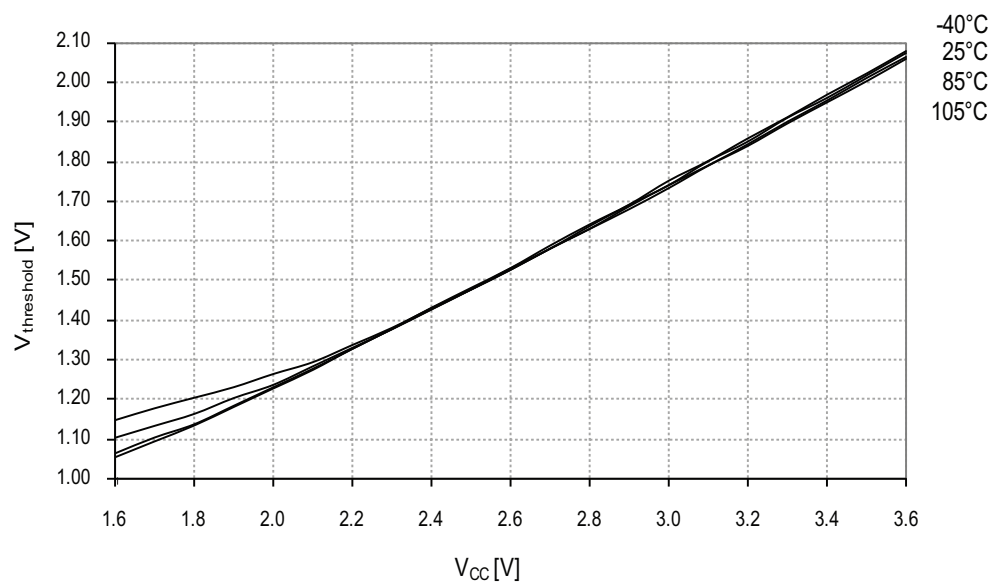
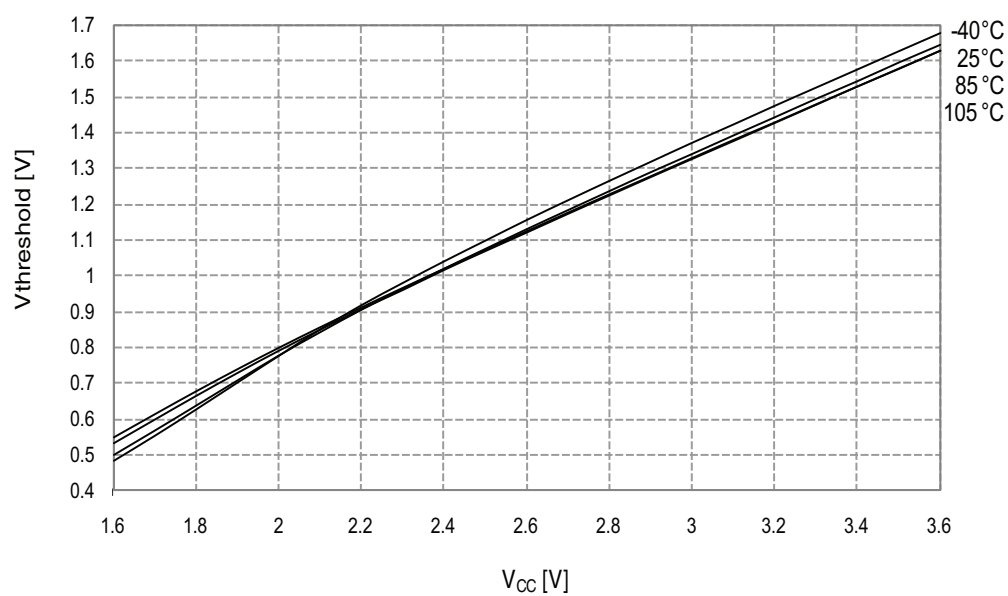


Figure 33-141. Reset Pin Input Threshold Voltage vs. V_{CC}

V_{IL} - Reset pin read as "0"



33.3.2 I/O Pin Characteristics

33.3.2.1 Pull-up

Figure 33-179. I/O Pin Pull-up Resistor Current vs. Input Voltage
 $V_{CC} = 1.8V$

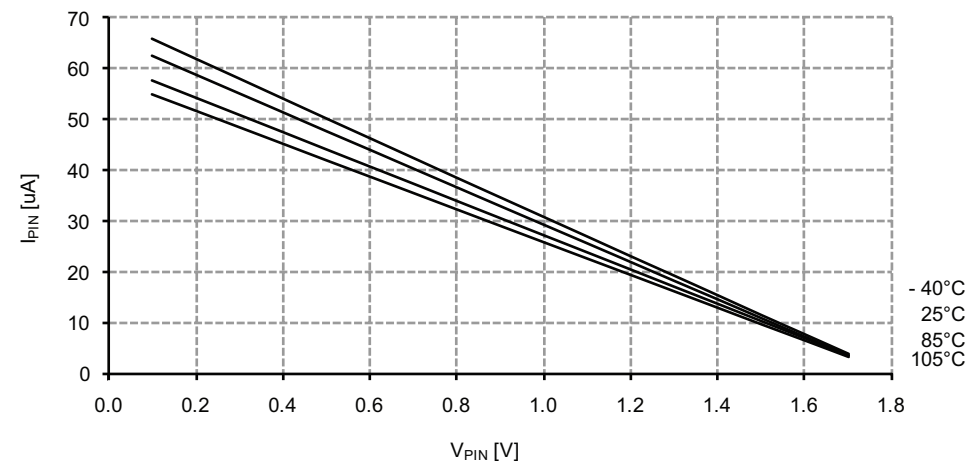


Figure 33-180. I/O Pin Pull-up Resistor Current vs. Input Voltage
 $V_{CC} = 3.0V$

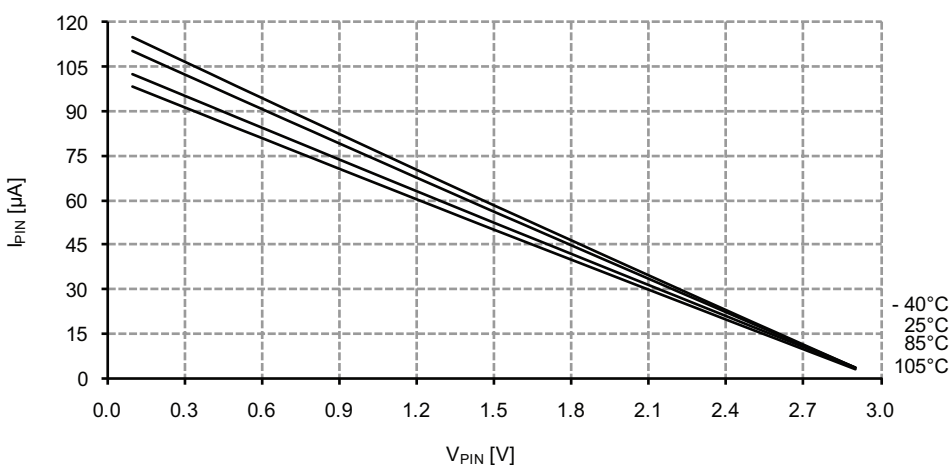
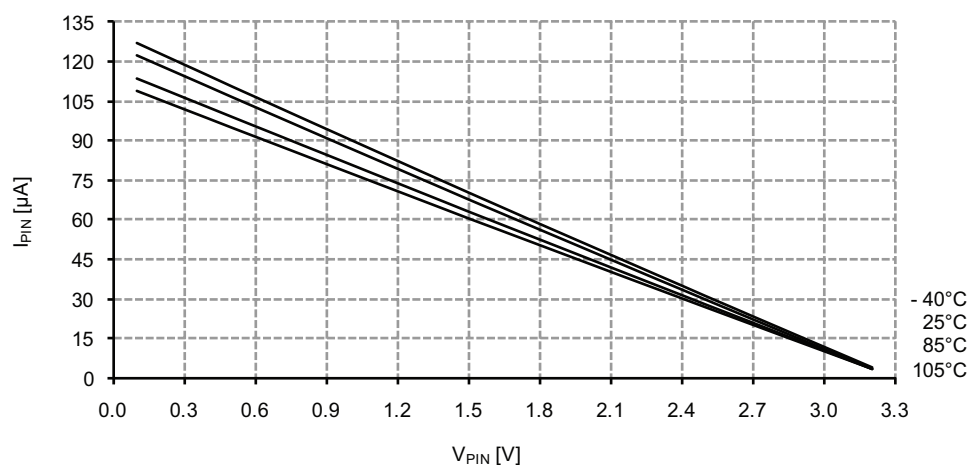


Figure 33-181. I/O Pin Pull-up Resistor Current vs. Input Voltage

$V_{CC} = 3.3V$



33.3.2.2 Output Voltage vs. Sink/Source Current

Figure 33-182. I/O Pin Output Voltage vs. Source Current

$V_{CC} = 1.8V$

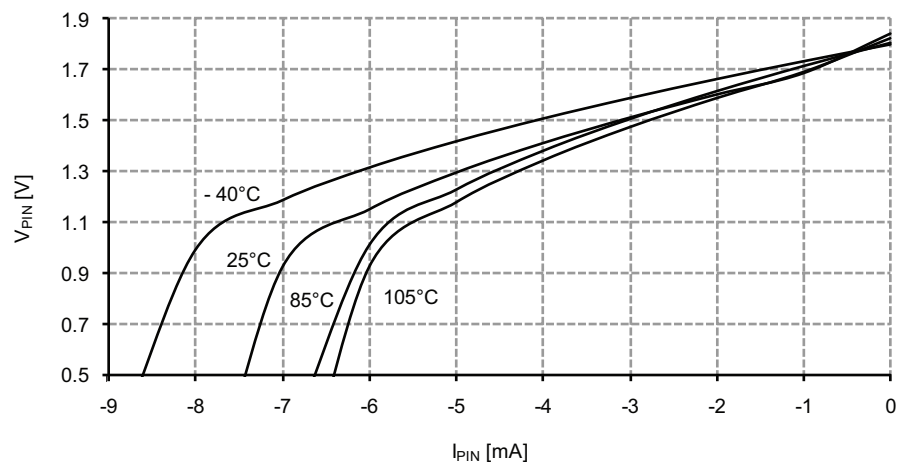


Figure 33-203. Gain Error vs. Temperature

$V_{CC} = 2.7V$, $V_{REF} = \text{external } 1.0V$

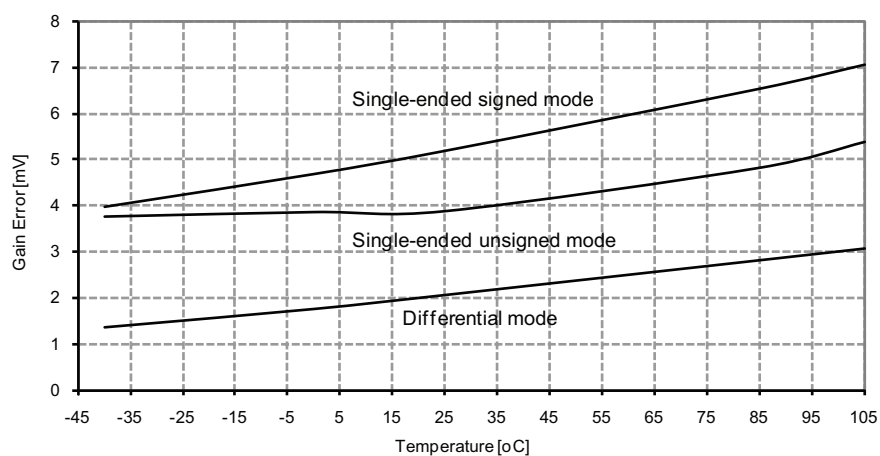


Figure 33-204. Offset Error vs. V_{CC}

$T = 25^{\circ}C$, $V_{REF} = \text{external } 1.0V$, ADC sampling speed = 500kps

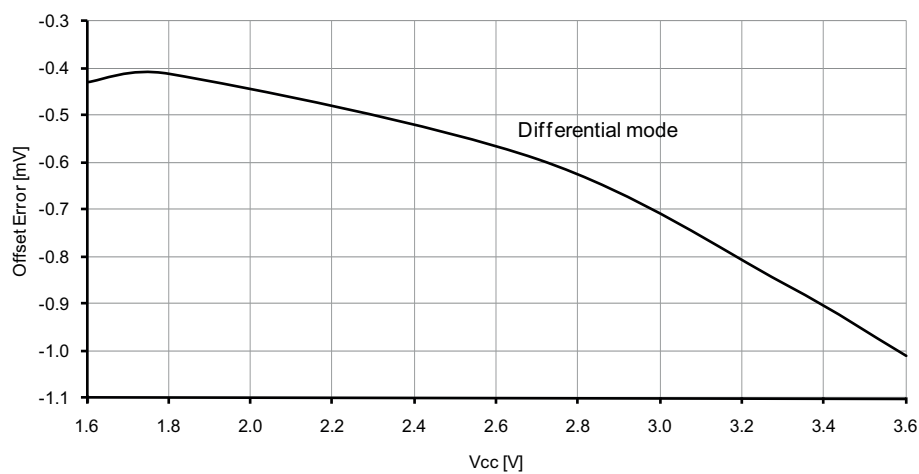


Figure 33-223. Reset Pin Pull-up Resistor Current vs. Reset Pin Voltage

$V_{CC} = 3.3V$

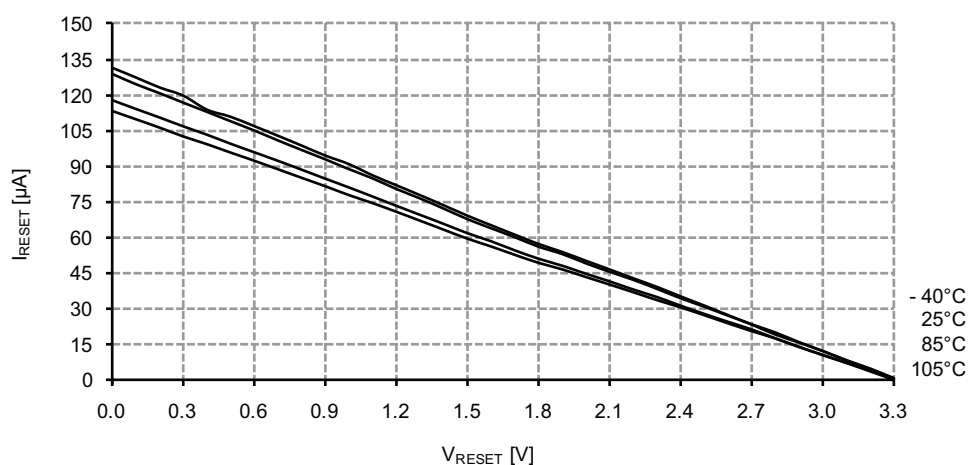


Figure 33-224. Reset Pin Input Threshold Voltage vs. V_{CC}

V_{IH} - Reset pin read as "1"

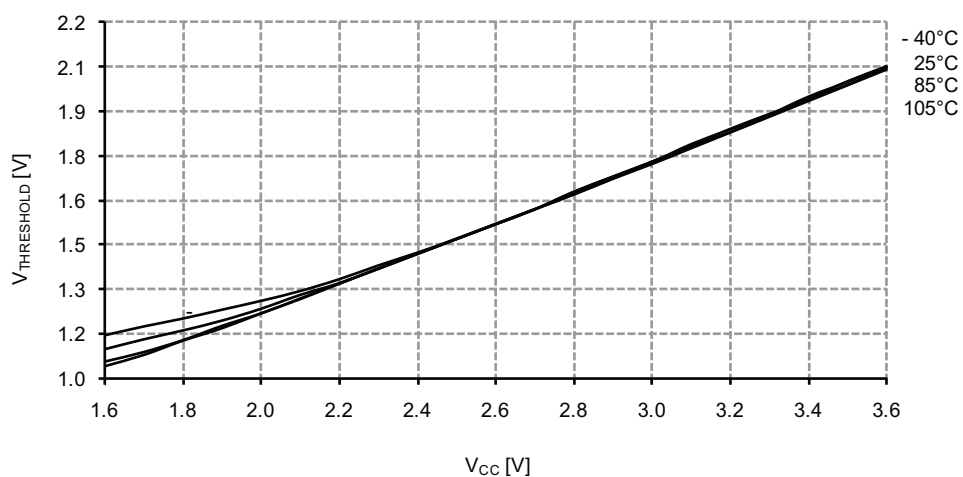


Figure 33-255. Idle Mode Supply Current vs. V_{CC}
 $f_{SYS} = 32\text{MHz}$ internal oscillator prescaled to 8MHz

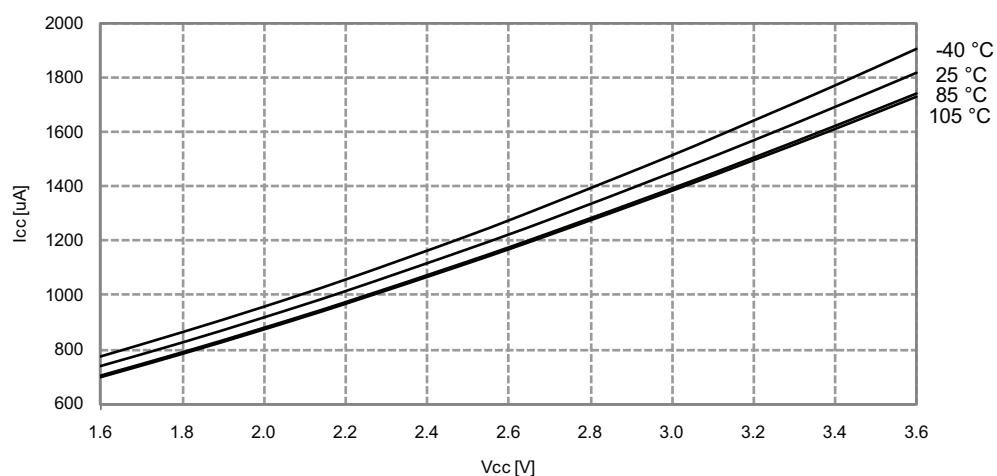
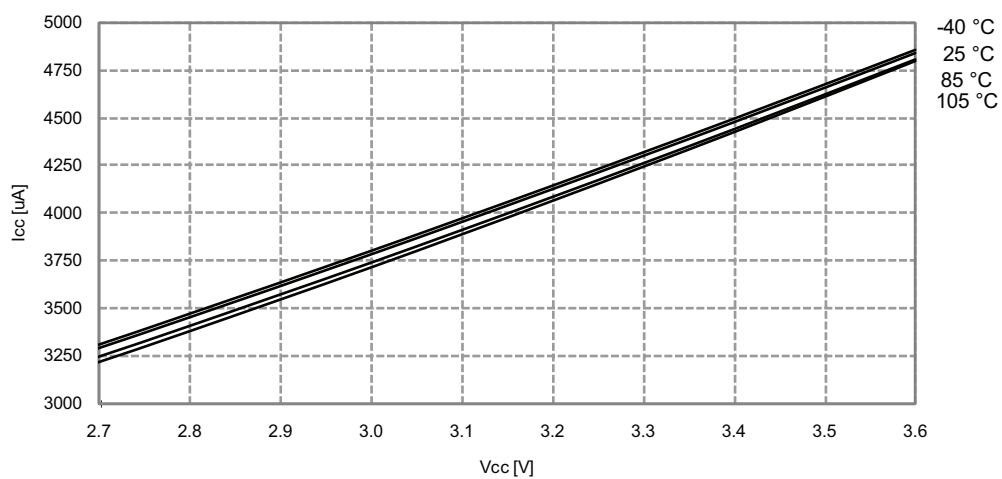


Figure 33-256. Idle Mode Current vs. V_{CC}
 $f_{SYS} = 32\text{MHz}$ internal oscillator



Problem fix/Workaround

Table 34-1. Configure PWM and CWCM According to this Table

PGM	CWCM	Description
0	0	PGM and CWCM disabled
0	1	PGM enabled
1	0	PGM and CWCM enabled
1	1	PGM enabled

10. PWM is not restarted properly after a fault in cycle-by-cycle mode

When the AWeX fault restore mode is set to cycle-by-cycle, the waveform output will not return to normal operation at first update after fault condition is no longer present.

Problem fix/Workaround

Do a write to any AWeX I/O register to re-enable the output.

11. BOD will be enabled after any reset

If any reset source goes active, the BOD will be enabled and keep the device in reset if the VCC voltage is below the programmed BOD level. During Power-On Reset, reset will not be released until VCC is above the programmed BOD level even if the BOD is disabled.

Problem fix/Workaround

Do not set the BOD level higher than VCC even if the BOD is not used.

12. Sampled BOD in Active mode will cause noise when bandgap is used as reference

Using the BOD in sampled mode when the device is running in Active or Idle mode will add noise on the bandgap reference for ADC and Analog Comparator.

Problem fix/Workaround

If the bandgap is used as reference for either the ADC or the Analog Comparator, the BOD must not be set in sampled mode.

13. EEPROM page buffer always written when NVM DATA0 is written

If the EEPROM is memory mapped, writing to NVM DATA0 will corrupt data in the EEPROM page buffer.

Problem fix/Workaround

Before writing to NVM DATA0, for example when doing software CRC or flash page buffer write, check if EEPROM page buffer active loading flag (EELoad) is set. Do not write NVM DATA0 when EELoad is set.

14. Pending full asynchronous pin change interrupts will not wake the device

Any full asynchronous pin-change Interrupt from pin 2, on any port, that is pending when the sleep instruction is executed, will be ignored until the device is woken from another source or the source triggers again. This applies when entering all sleep modes where the System Clock is stopped.

Problem fix/Workaround

None.

15. Pin configuration does not affect Analog Comparator output

The Output/Pull and inverted pin configuration does not affect the Analog Comparator output.

35.138135G – 08/10	320
35.148135F – 02/10	320
35.158135E – 02/10	321
35.168135D – 12/09	321
35.178135C – 10/09	321
35.188135B – 09/09	321
35.198135A – 03/09	322

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